PNP Current Driver Transistor

NZT753

This device is designed for power amplifier, regulator and switching circuits where speed is important. Sourced from Process 5P.

ABSOLUTE MAXIMUM RATINGS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$ (Notes 1, 2)

| Symbol | Parameter | Value | Unit |
|-----------------------------------|---|-------------|------|
| V _{CEO} | Collector-Emitter Voltage | -100 | V |
| V _{CBO} | Collector-Base Voltage | -120 | V |
| V _{EBO} | Emitter-Base Voltage | -5.0 | V |
| Ι _C | Collector Current – Continuous | -4.0 | А |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

These are steady limits. The factory should be consulted on application involving pulsed or low duty cycle operations.

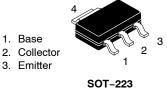
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted.) (Note 3)

| Symbol | Parameter | Max | Unit |
|----------------|---|------------|------------|
| P _D | Total Device Dissipation Derate above 25°C | 1.2 9.7 | W mW/°C |
| R_{\thetaJA} | Thermal Resistance, Junction to Ambient | 103 | °C/W |

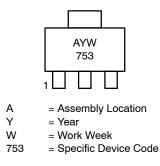
 Device mounted on FR-4PCB 36 mm × 18 mm × 1.5 mm; mounting pad for the collector lead min. 6 cm².

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.) (Note 4)



CASE 318H

MARKING DIAGRAM



ORDERING INFORMATION

| Device | ce Package Shipping | |
|--------|----------------------|---------------------|
| NZT753 | SOT-223 (Pb-Free) | 4,000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

| Symbol | Parameter | Test Conditions | Min | Max | Unit |
|-----------------------|--------------------------------------|---|-----------------|-------------|----------|
| OFF CHAF | ACTERISTICS | | | | |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_{\rm C} = -10$ mA, $I_{\rm B} = 0$ | -100 | - | V |
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_{\rm C} = -100 \ \mu A, \ I_{\rm E} = 0$ | -120 | - | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_{E} = -100 \ \mu A, \ I_{C} = 0$ | -5.0 | - | V |
| I _{CBO} | Collector-Base Cutoff Current | $V_{CB} = -100 \text{ V}, I_E = 0$ $V_{CB} = -100 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C}$ | | -0.1 -10 | μΑ μΑ |
| I _{EBO} | Emitter-Base Cutoff Current | $V_{EB} = -4 V, I_{C} = 0$ | - | -0.1 | μA |
| ON CHAR | ACTERISTICS (Note 4) | | | | - |
| h _{FE} | DC Current Gain | $V_{CE} = -2.0 \text{ V}, \text{ I}_{C} = -50 \text{ mA} \\ V_{CE} = -2.0 \text{ V}, \text{ I}_{C} = -500 \text{ mA} \\ V_{CE} = -2.0 \text{ V}, \text{ I}_{C} = -1.0 \text{ A} \\ \end{cases}$ | 70 100 55 | 300 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = -1.0 A, I _C = -50 mA | | -0.3 | V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | I _C = −1.0 A, I _B = −100 mA | | -1.25 | V |

NZT753

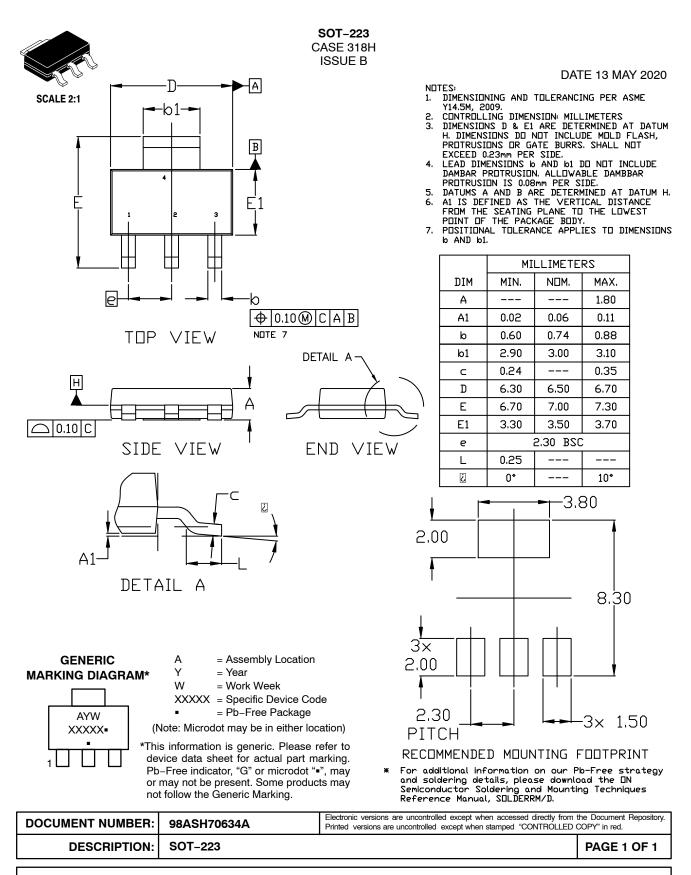
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted.) (Note 4) (continued)

| Symbol | Parameter | Test Conditions | Min | Max | Unit |
|------------------------------|-------------------------|---|-----|------|------|
| ON CHARACTERISTICS (Note 4) | | | | | |
| V _{BE} (on) | Base-Emitter On Voltage | $V_{CE} = -2.0 \text{ V}, \text{ I}_{C} = -1.0 \text{ A}$ | - | -1.0 | V |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| f _T | Transition Frequency | $V_{CE} = -5 \text{ V}, \text{ I}_{C} = -100 \text{ mA}, \text{ f} = 100 \text{ MHz}$ | 75 | _ | MHz |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

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PACKAGE DIMENSIONS



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